

Vishay Siliconix

Dual P-Channel 20-V (D-S) MOSFET

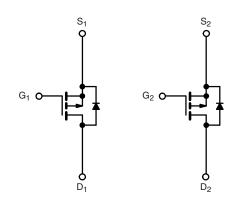
PRODUCT SUMMARY			
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	
- 20	0.200 at V _{GS} = - 4.5 V	± 1.8	
	0.235 at V _{GS} = - 3.6 V	± 1.6	
	0.340 at V _{GS} = - 2.5 V	± 1.3	

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs: 2.5 V Rated
- Compliant to RoHS Directive 2002/95/EC



Available



Ordering Information: Si3909DV-T1-E3 (Lead (Pb)-free) Si3909DV-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T	_A = 25 °C, unle	ss otherwise n	noted		
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 20	v	
Gate-Source Voltage		V _{GS}	± 12	V	
Continuous Drain Current (T _{.I} = 150 °C) ^{a, b}	T _A = 25 °C	- I _D	± 1.8		
Continuous Drain Current $(1_J = 150^{\circ}C)^{\circ}$	T _A = 70 °C		± 1.2		
Pulsed Drain Current		I _{DM}	± 7	A	
Continuous Diode Current (Diode Conduction) ^{a, b}		۱ _S	- 1.05		
Marine Draw Distingtion a b	T _A = 25 °C	PD	1.15	w	
Maximum Power Dissipation ^{a, b}	T _A = 70 °C		0.73	7	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mauianum lunation to Ambienta	t ≤ 5 s	– R _{thJA}	93	110	
Maximum Junction-to-Ambient ^a	Steady State		130	150	°C/W
Maximum Junction-to-Lead	Steady State	R _{thJL}	75	90	

Notes:

a. Surface Mounted on FR4 board. b. $t \leq 5 \mbox{ s.}$

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TSOP-6 Top View G1 D1 6 3 mm S1 S2 5 2 G2 D2 3 4 – 2.85 mm – ł

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 0.5			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA	
	I _{DSS}	$V_{DS} = -16 V, V_{GS} = 0 V$		- 1			
Zero Gate Voltage Drain Current		V_{DS} = - 16 V, V_{GS} = 0 V, T_{J} = 55 °C	- 5			μA	
On-State Drain Current ^a	I _{D(on)}	V_{DS} \leq - 5 V, V_{GS} = - 4.5 V	- 5			Α	
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -1.8 \text{ A}$		0.160	0.200	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 3.6 V, I _D = - 1.6 A		0.190	0.235		
		V _{GS} = - 2.5 V, I _D = - 1 A		0.280	0.340		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 1.8 A		3.6		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.05 A, V _{GS} = 0 V		- 0.83	- 1.1	V	
Dynamic ^b							
Total Gate Charge	Qg			2.7	4.0		
Gate-Source Charge	Q _{gs}	$_{\rm S}$ V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 1.8 A		0.4		nC	
Gate-Drain Charge	Q _{gd}			0.6			
Turn-On Delay Time	t _{d(on)}			11	17		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		34	50		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_{\text{D}}\cong$ - 1 A, V_{GEN} = - 4.5 V, R_{g} = 6 Ω		19	30	ns	
Fall Time	t _f			24	36		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.05 A, dI/dt = 100 A/μs		20	40		

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

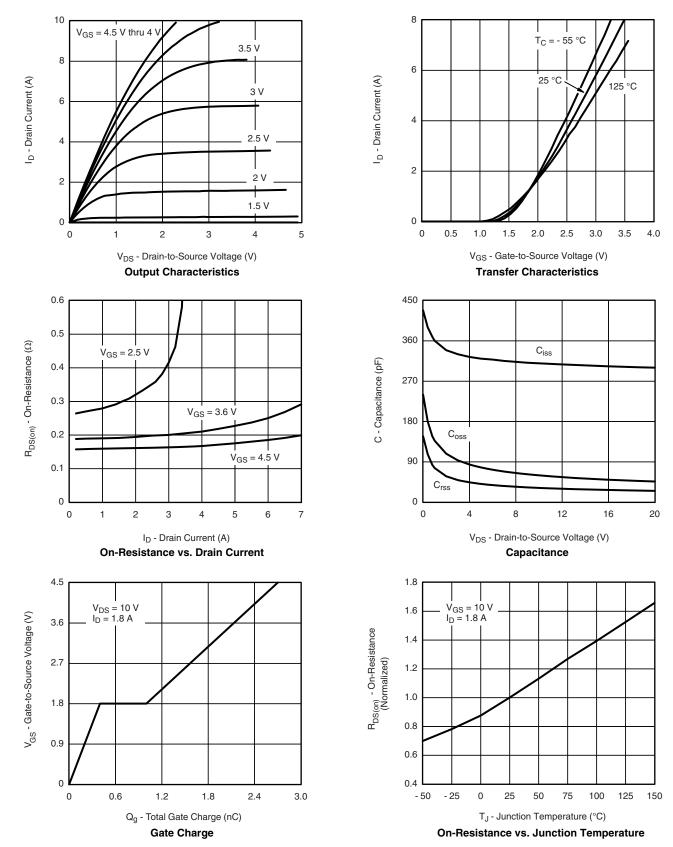
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



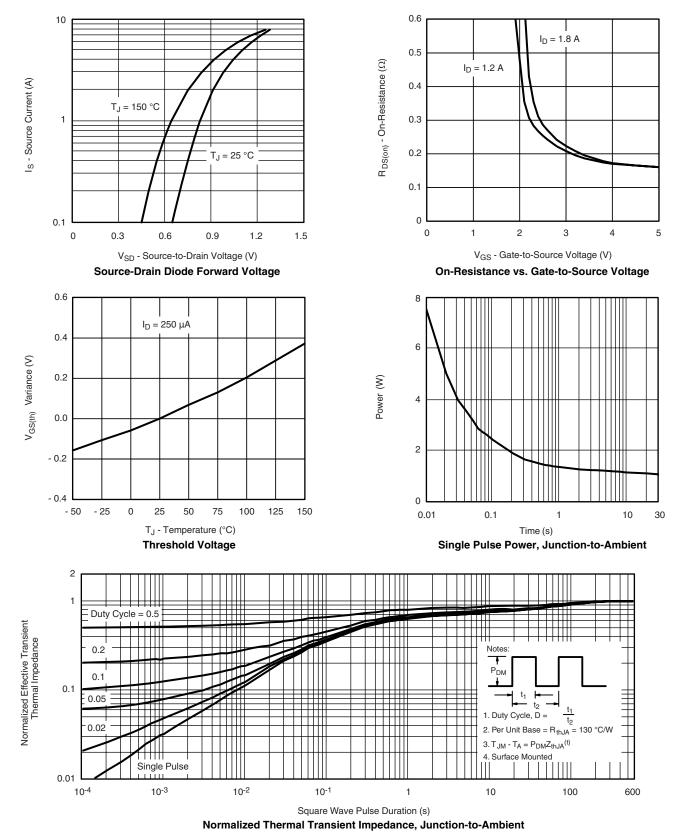
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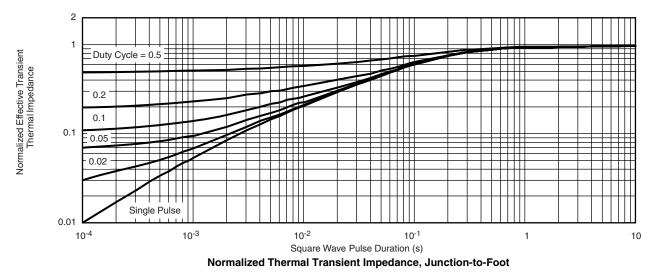




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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg270968.



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